

LTC6930-X.XX

32.768kHz to 8.192MHz Precision µPower Oscillators

FEATURES

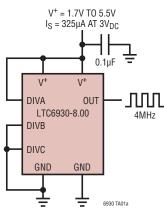
- Frequency Error <0.09% Max at 25°C</p>
- Start-Up Time <110µs at All Frequencies</p>
- 1.7V to 5.5V Single Supply Operation
- 105µA Typical Supply Current at 32kHz, V⁺ = 3V
- 490µA Typical Supply Current at 8MHz, V⁺ = 3V
- Typical RMS Period Jitter <0.15% at V⁺ = 3V
- No External Components to Set Frequency
- 5 Options Cover 32.768kHz to 8.192MHz: LTC6930-4.19: 4.194304MHz ÷ N LTC6930-5.00: 5.000000MHz ÷ N LTC6930-7.37: 7.373800MHz ÷ N LTC6930-8.00: 8.000000MHz ÷ N LTC6930-8.19: 8.192000MHz ÷ N Where N = 1, 2, 4, 8, 16, 32, 64, 128 (N Determined by State of DIVA, DIVB, DIVC Pins)
- –40°C to 125°C Operating Temperature Range
- Tiny 2mm × 3mm DFN or MS8 Package

APPLICATIONS

- Digitally Controlled Oscillator
- Microprocessor Clock
- Power Supply Clock
- Portable and Battery Operated Devices

TYPICAL APPLICATION

4MHz Micropower Clock Generator

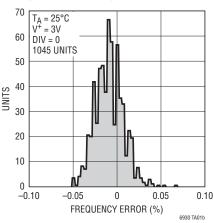


DESCRIPTION

The LTC®6930 series is a family of very low power precision silicon oscillators with a frequency error less than 0.09%. For each oscillator, the user can select one of 8 frequencies between 32.768kHz and 8.192MHz. Based on a fixed master oscillator frequency, internal frequency dividers between 1 and 128 provide the 8 different frequencies. The LTC6930 requires no external components other than power supply bypass capacitors. Requiring only a single 1.7V to 5.5V supply enables operation from a single Li-lon cell or 2 AA alkaline cells.

The LTC6930 features a proprietary control architecture that allows for ultralow power operation while maintaining industry leading accuracy and jitter specifications. The exceptionally fast start-up time, combined with the low power consumption, is ideal for battery operated applications with frequent power-up cycles.

Any frequency from 32.768kHz to 8.192MHz can be provided by the factory. Minimum order sizes apply for custom frequencies. Please consult LTC Marketing for details.



Typical Frequency Error Distribution

ABSOLUTE MAXIMUM RATINGS

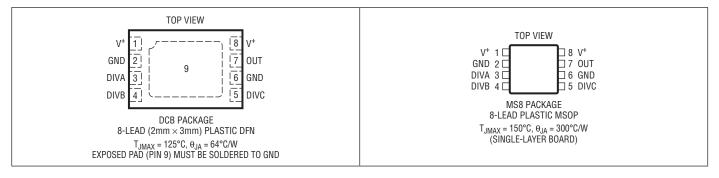
(Note 1)

Total Supply Voltage	
(V ⁺ to GND)	–0.3V to 6V
Any Input Pin to GND	
(DIV Pins)	0.3V to V ⁺ + 0.3V
Operating Temperature Range (N	lote 2)
LTC6930C	40°C to 85°C
LTC69301	40°C to 85°C
LTC6930H	40°C to 125°C

Specified Temperature Range (Note 3)

LTC6930C	0°C to 70°C
LTC69301	40°C to 85°C
LTC6930H	40°C to 125°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering,	10 sec) 300°C

PIN CONFIGURATION



ORDER INFORMATION

Lead Free Finish

TAPE AND REEL (MINI)	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC6930CDCB-4.19#TRMPBF	LTC6930CDCB-4.19#TRPBF	LCKT	8-Lead ($2mm \times 3mm$) Plastic DFN	0°C to 70°C
LTC6930IDCB-4.19#TRMPBF	LTC6930IDCB-4.19#TRPBF	LCKT	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 85°C
LTC6930HDCB-4.19#TRMPBF	LTC6930HDCB-4.19#TRPBF	LCKT	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 125°C
LTC6930CDCB-5.00#TRMPBF	LTC6930CDCB-5.00#TRPBF	LCKV	8-Lead ($2mm \times 3mm$) Plastic DFN	0°C to 70°C
LTC6930IDCB-5.00#TRMPBF	LTC6930IDCB-5.00#TRPBF	LCKV	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 85°C
LTC6930HDCB-5.00#TRMPBF	LTC6930HDCB-5.00#TRPBF	LCKV	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 125°C
LTC6930CDCB-7.37#TRMPBF	LTC6930CDCB-7.37#TRPBF	LCKW	8-Lead ($2mm \times 3mm$) Plastic DFN	0°C to 70°C
LTC6930IDCB-7.37#TRMPBF	LTC6930IDCB-7.37#TRPBF	LCKW	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 85°C
LTC6930HDCB-7.37#TRMPBF	LTC6930HDCB-7.37#TRPBF	LCKW	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 125°C
LTC6930CDCB-8.00#TRMPBF	LTC6930CDCB-8.00#TRPBF	LCKX	8-Lead ($2mm \times 3mm$) Plastic DFN	0°C to 70°C
LTC6930IDCB-8.00#TRMPBF	LTC6930IDCB-8.00#TRPBF	LCKX	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 85°C
LTC6930HDCB-8.00#TRMPBF	LTC6930HDCB-8.00#TRPBF	LCKX	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 125°C
LTC6930CDCB-8.19#TRMPBF	LTC6930CDCB-8.19#TRPBF	LCKY	8-Lead ($2mm \times 3mm$) Plastic DFN	0°C to 70°C
LTC6930IDCB-8.19#TRMPBF	LTC6930IDCB-8.19#TRPBF	LCKY	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 85°C
LTC6930HDCB-8.19#TRMPBF	LTC6930HDCB-8.19#TRPBF	LCKY	8-Lead ($2mm \times 3mm$) Plastic DFN	-40°C to 125°C



6930fb

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ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LTC6930IMS8-4.19#PBF	LTC6930IMS8-4.19#TRPBF	LTCKZ	8-Lead Plastic MSOP	-40°C to 85°C
LTC6930HMS8-4.19#PBF	LTC6930HMS8-4.19#TRPBF	LTCKZ	8-Lead Plastic MSOP	-40°C to 125°C
LTC6930CMS8-5.00#PBF	LTC6930CMS8-5.00#TRPBF	LTCLB	8-Lead Plastic MSOP	0°C to 70°C
LTC6930IMS8-5.00#PBF	LTC6930IMS8-5.00#TRPBF	LTCLB	8-Lead Plastic MSOP	-40°C to 85°C
LTC6930HMS8-5.00#PBF	LTC6930HMS8-5.00#TRPBF	LTCLB	8-Lead Plastic MSOP	-40°C to 125°C
LTC6930CMS8-7.37#PBF	LTC6930CMS8-7.37#TRPBF	LTCLC	8-Lead Plastic MSOP	0°C to 70°C
LTC6930IMS8-7.37#PBF	LTC6930IMS8-7.37#TRPBF	LTCLC	8-Lead Plastic MSOP	-40°C to 85°C
LTC6930HMS8-7.37#PBF	LTC6930HMS8-7.37#TRPBF	LTCLC	8-Lead Plastic MSOP	-40°C to 125°C
_TC6930CMS8-8.00#PBF	LTC6930CMS8-8.00#TRPBF	LTCLD	8-Lead Plastic MSOP	0°C to 70°C
_TC6930IMS8-8.00#PBF	LTC6930IMS8-8.00#TRPBF	LTCLD	8-Lead Plastic MSOP	-40°C to 85°C
_TC6930HMS8-8.00#PBF	LTC6930HMS8-8.00#TRPBF	LTCLD	8-Lead Plastic MSOP	-40°C to 125°C
LTC6930CMS8-8.19#PBF	LTC6930CMS8-8.19#TRPBF	LTCLF	8-Lead Plastic MSOP	0°C to 70°C
_TC6930IMS8-8.19#PBF	LTC6930IMS8-8.19#TRPBF	LTCLF	8-Lead Plastic MSOP	-40°C to 85°C
LTC6930HMS8-8.19#PBF	LTC6930HMS8-8.19#TRPBF	LTCLF	8-Lead Plastic MSOP	-40°C to 125°C

*Temperature grades are identified by a label on the shipping container.

Consult LTC Marketing for parts specified with wider operating temperature ranges.

Consult LTC Marketing for information on lead based finish parts.

For more information on lead free part marking, go to: http://www.linear.com/leadfree/

For more information on tape and reel specifications, go to: http://www.linear.com/tapeandreel/

AC ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25$ °C. Unless otherwise noted, specifications apply over the full range of operating supply voltage and frequency output: V⁺ = 1.7V to 5.5V and all DIV settings with C_{LOAD} = 5pF, R_{LOAD} = ∞ .

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Δfi	Initial Frequency Accuracy	$DIVA = DIVB = DIVC = 0$, $T_A = 25^{\circ}C$, $V^+ = 3V$			0.08	0.09	%
Δf	Frequency Accuracy (Note 4)	V ⁺ = 3V - 3.6V LTC6930C LTC6930I LTC6930H	•		±0.1 ±0.1 ±0.1	±0.45 ±0.65 ±1	% % %
		V ⁺ = 2V - 3.6V LTC6930C LTC6930I LTC6930H	•		±0.1 ±0.1 ±0.1	±0.52 ±0.65 ±1.1	% %
		V ⁺ = 1.7V - 5.5V LTC6930C LTC6930I LTC6930H	•		±0.1 ±0.1 ±0.1	±0.8 ±0.95 ±1.3	% %
$\Delta f/\Delta T$	Frequency Drift Over Temperature	MS8 Package DCB Package	•		0.0001 0.001		%/°C %/°C
$\Delta f/\Delta V$	Frequency Drift Over Supply		•		0.07		%/V
	Long-Term Frequency Stability	(Note 5)	•		30		ppm/√kHr



AC ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. Unless otherwise noted, specifications apply over the full range of operating supply voltage and frequency output: V⁺ = 1.7V to 5.5V and all DIV settings with C_{LOAD} = 5pF, R_{LOAD} = ∞ .

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
	RMS Period Jitter	$DIVA = DIVB = DIVC = 0, V^+ = 3V$				
		LTC6930-4.19 (4.194304MHz)		320		ps RMS
				1.7		nsp-p
		LTC6930-5.00 (5.000000MHz)		225		ps RMS
				1.2		ns _{P-P}
		LTC6930-7.37 (7.372800MHz)		180		ps RMS
				0.97		ns _{P-P}
		LTC6930-8.00 (8.000000MHz)		130		ps RMS
				0.8		NSP-P
		LTC6930-8.19 (8.192000MHz)		130		ps RMS
				0.8		ns _{P-P}

DC ELECTRICAL CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25$ °C. Unless otherwise noted, specifications apply over the full range of operating supply voltage and frequency output: V⁺ = 1.7V to 5.5V and all DIV settings with C_{LOAD} = 5pF, R_{LOAD} = ∞ .

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _S	Supply Voltage Applied Between V ⁺ and GND		•	1.7		5.5	V
I _{S,DC}	V ⁺ Combined Supply Current	$ \begin{array}{l} LTC6930-4.19 \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 1.7V \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 3V \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 5.5V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 1.7V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 3V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 5.5V \\ \end{array} $			170 260 490 80 105 130	290 420 750 160 190 355	Ац Ац Ац Ац Ац
		$ \begin{array}{c} LTC6930-5.00 \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 1.7V \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 3V \\ DIVA = DIVB = DIVC = 0, \ V^{+} = 5.5V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 1.7V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 3V \\ DIVA = DIVB = DIVC = 1, \ V^{+} = 5.5V \\ \end{array} $	• • •		201 307 579 95 124 154	430 570 960 176 212 375	Ац Ац Ац Ац Ац
I _{S,DC}	V ⁺ Combined Supply Current	$ \begin{array}{c} LTC6930-7.37 \\ DIVA = DIVB = DIVC = 0, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 0, V^+ = 3V \\ DIVA = DIVB = DIVC = 0, V^+ = 5.5V \\ DIVA = DIVB = DIVC = 1, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 1, V^+ = 3V \\ DIVA = DIVB = DIVC = 1, V^+ = 5.5V \\ \end{array} $	• • •		296 453 853 139 183 226	480 660 1310 220 273 440	Ац Ац Ац Ац Ац
		$ \begin{array}{l} LTC6930-8.00 \\ DIVA = DIVB = DIVC = 0, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 0, V^+ = 3V \\ DIVA = DIVB = DIVC = 0, V^+ = 5.5V \\ DIVA = DIVB = DIVC = 1, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 1, V^+ = 3V \\ DIVA = DIVB = DIVC = 1, V^+ = 5.5V \\ \end{array} $	• • •		321 491 926 151 198 246	520 740 1380 240 295 475	Ац Ац Ац Ац Ац
		$ \begin{array}{c} LTC6930-8.19 \\ DIVA = DIVB = DIVC = 0, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 0, V^+ = 3V \\ DIVA = DIVB = DIVC = 0, V^+ = 5.5V \\ DIVA = DIVB = DIVC = 1, V^+ = 1.7V \\ DIVA = DIVB = DIVC = 1, V^+ = 3V \\ DIVA = DIVB = DIVC = 1, V^+ = 5.5V \\ \end{array} $			310 500 880 150 190 210	490 760 1400 270 325 540	Ац Ац Ац Ац Ац
V _{IH}	Minimum High Level Input Voltage, All Digital Input Pins		•		1.25	1.4	V

DC ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_A = 25°C. Unless otherwise noted, specifications apply over the full range of operating supply voltage and frequency output: V⁺ = 1.7V to 5.5V and all DIV settings with C_{LOAD} = 5pF, R_{LOAD} = ∞ .

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{IL}	Maximum Low Level Input Voltage, All Digital Input Pins		•	0.7	1.25		V
I _{IN}	Digital Input Leakage Current, All Digital Input Pins	$0 < V_{IN} < V^+$	•			±1	μA
R _{OUT}	Output Resistance	OUT Pin, V ⁺ = 3V			40		Ω
V _{OH}	High Level Output Voltage	$ \begin{array}{l} {\sf DIVA} = {\sf DIVB} = {\sf DIVC} = 0, {\sf No} {\sf Load} \\ {\sf V}^+ = 5.5{\sf V} \\ {\sf V}^+ = 3{\sf V} \\ {\sf V}^+ = 2{\sf V} \\ {\sf V}^+ = 1.7{\sf V} \end{array} $	•	5.4 2.9 1.8	5.5 3 2 1.7		V V V V
		DIVA = DIVB = DIVC = 0, $1k\Omega$ Load to GND V ⁺ = 5.5V V ⁺ = 3V V ⁺ = 2V V ⁺ = 1.7V	•	5 2.6 1.5	5.2 2.7 1.6 1.5		V V V V
V _{OL}	Low Level Output Voltage	DIVA = DIVB = DIVC = 0, No Load V ⁺ = 5.5V V ⁺ = 3V V ⁺ = 2V V ⁺ = 1.7V	•		0 0 0 0	0.1 0.1 0.1	V V V V
		$ \begin{array}{c} {\sf DIVA} = {\sf DIVB} = {\sf DIVC} = 0, \ 1 k\Omega \ {\sf Load} \ to \ V^+ \\ {\sf V}^+ = 5.5 {\sf V} \\ {\sf V}^+ = 3 {\sf V} \\ {\sf V}^+ = 2 {\sf V} \\ {\sf V}^+ = 1.7 {\sf V} \end{array} $	•		0.3 0.3 0.3 0.3	0.7 0.5 0.35	V V V V

TIMING CHARACTERISTICS The • denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25$ °C. Unless otherwise noted, specifications apply over the full range of operating supply voltage and frequency output: V⁺ = 1.7V to 5.5V and f_{OUT} = 32.768kHz to 8.192MHz with C_{LOAD} = 5pF, R_{LOAD} = ∞ .

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
t _{rf}	Output Rise/Fall Time (10% to 90%)	V ⁺ = 3V			3		ns
DCY	Duty Cycle	DIVA = DIVB = DIVC = 0; V^+ = 2V to 5.5V DIVA = DIVB = DIVC = 0 DIVA or DIVB or DIVC \neq 0	•	35 35 48	50 50 50	65 70 52	% % %
D _{DIV}	DIV to F _{OUT} Delay	Edge of DIV Signal to 1st Accurate Output Cycle			1		Cycle
D _{PON}	Power On Delay	V ⁺ > 1.7V to 1st Accurate Output Cycle				110	μs

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: LTC6930C is guaranteed functional over the operating range of -40°C to 85°C.

Note 3: The LTC6930C is guaranteed to meet specified performance from 0°C to 70°C. The LTC6930C is designed, characterized and expected to meet specified performance from -40°C to 85°C but is not tested or QA sampled at these temperatures. The LTC6930I is guaranteed to meet specified performance from -40°C to 85°C. The LTC6930H is guaranteed to meet specified performance from -40°C to 125°C.

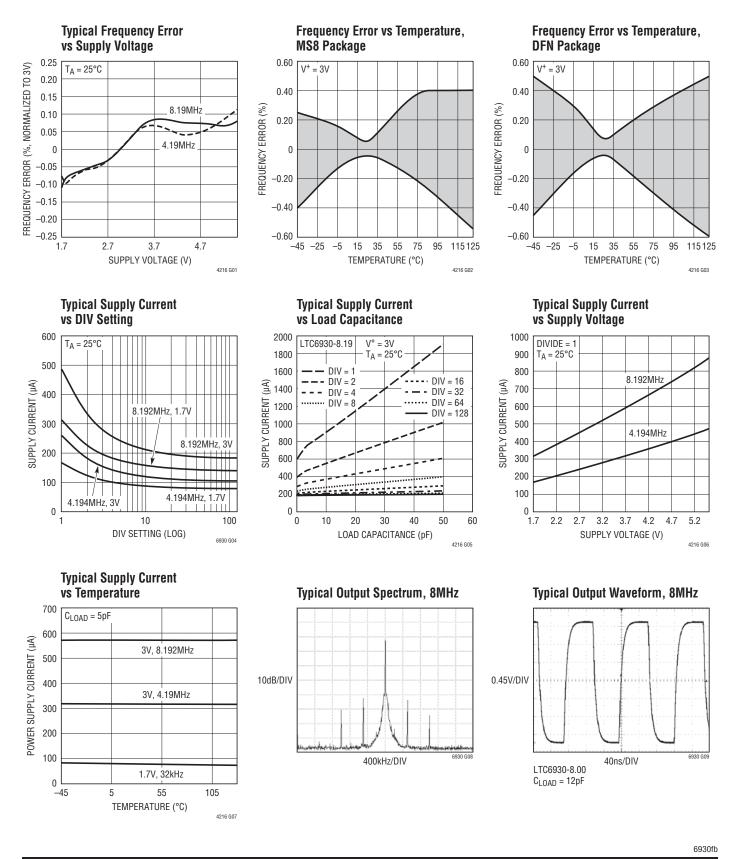
Note 4: Frequency accuracy and frequency drift are defined as deviation from the nominal frequency or the nominal frequency divided by the integer set through the DIV pins for each part. The nominal frequency for the LTC6930 family of parts are defined as follows:

v	L100000	iuniny c	n parto aro donnoa do ron
	LTC6930-	4.19	f _{NOM} = 4.194304MHz
	LTC6930-	·5.00	f _{NOM} = 5.000000MHz
	LTC6930-	7.37	f _{NOM} = 7.372800MHz
	LTC6930-	·8.00	f _{NOM} = 8.000000MHz
	LTC6930-	8.19	f _{NOM} = 8.192000MHz

Note 5: Long-term drift of silicon oscillators is primarily due to the movement of ions and impurities within the silicon and is tested at 30°C under otherwise nominal operating conditions. Long-term drift is specified as ppm/ \sqrt{kHr} due to the typically non-linear nature of the drift. To calculate drift for a set time period, translate that time into thousands of hours, take the square root and multiply by the typical drift number. For instance, a year is 8.77kHr and would yield a drift of 89ppm at 30ppm/ \sqrt{kHr} . Drift without power applied to the device may be approximated as 1/10th of the drift with power, or $3ppm/\sqrt{kHr}$ for a $30ppm/\sqrt{kHr}$ device.

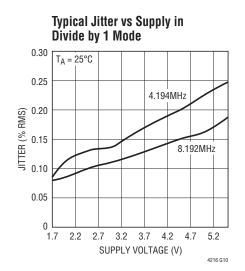
Downloaded from Elcodis.com electronic components distributor

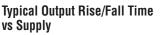
TYPICAL PERFORMANCE CHARACTERISTICS

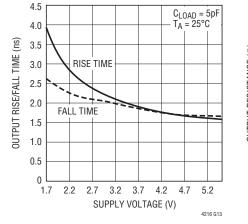




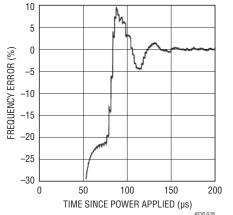
TYPICAL PERFORMANCE CHARACTERISTICS

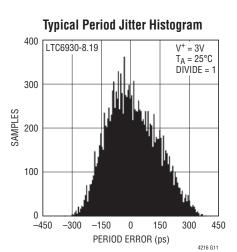




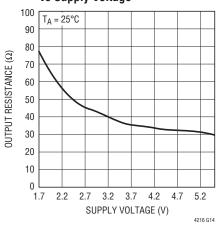




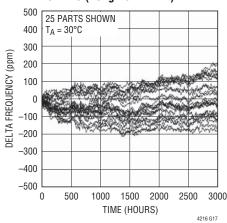


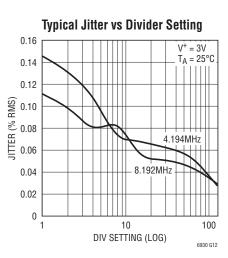


Typical Output Resistance vs Supply Voltage

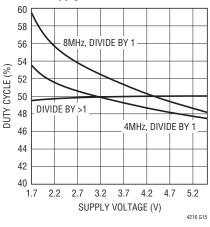


Typical Frequency Error vs Time (Long-Term Drift)

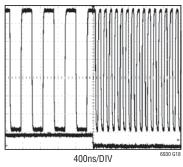




Typical Output Duty Cycle vs Supply and Divide Ratio



Typical Output Waveform at DIV Pin Change



PIN FUNCTIONS

V⁺ (**Pins 1, 8**): Positive Supply Pins. Each supply pin should be bypassed directly to the neighboring GND pin with a 0.1μ F ceramic capacitor, and must be externally connected to the other V⁺ pin (see recommended layout).

GND (Pins 2, 6): Ground Pins. Each should be connected to a low inductance ground plane and must be connected to the other GND pin and on the DFN package, Pin 9.

DIVA, DIVB, DIVC (Pins 3, 4, 5): Output Prescaler. Selects divide ratio of master oscillator frequency used to generate the output. See frequency setting Table 1 for function. These are standard CMOS logic inputs with a typical threshold of 1.25V

OUT (Pin 7): Oscillator Output. Drives up to 50pF capacitive or 1k resistive load (Refer to Supply Current vs Load Capacitance in Typical Performance Characteristics section). Typical series resistance is less than 80Ω at 1.7V and less than 40Ω at 3V supply. The output trace should be isolated as much as possible from Pin 1 and Pin 2. The OUT pin is held low during start-up, and remains free from glitches and runt pulses during DIV pin switching.

Exposed Pad (Pin 9, DFN Only): The Exposed Pad must be soldered to a PCB plane connected to GND.

APPLICATIONS INFORMATION

Theory of Operation

The LTC6930 is an entirely self contained all silicon oscillator which consists of a master oscillator, a control loop and an output frequency divider. The master oscillator operates between 4.2MHz and 8.2MHz and is factory programmed. The master oscillator frequency is accurately maintained over temperature and environmental extremes by a proprietary switched capacitor feedback loop.

Each LTC6930 oscillator has an output frequency divider which is controlled via the DIVA, DIVB and DIVC inputs. The divider divides the master frequency by 2^N , where N is an integer from 0 to 7 (divider ranges from 1 to 128). See Table 1 for the full range of frequencies covered by the LTC6930 family.

The presence of two sets of supply pins and careful internal layout reduce interference between the oscillator output and the control loop. This allows the LTC6930 to provide a clean output frequency with very little deterministic jitter, even in cases of heavy output loading and noisy operating environments.

The supply voltage of the LTC6930 is internally regulated to maintain a very low frequency drift over supply.

Output Driver and Loading

The output of the LTC6930 is a low series resistance 40Ω CMOS driver with controlled rise/fall times to limit RF interference and power supply spikes generated by the output while preserving the ability to drive low impedance loads. Especially at high frequencies, the capacitive loading of the output of the LTC6930 may cause the majority of the power supply dissipation of the part.

The LTC6930 supply current is specified at an output load of 5pF, which is equivalent to two standard HC logic inputs. The portion of the power supply current needed to drive a capacitive load may be calculated as:

$$I_{\text{SUPPLY}} = C_{\text{LOAD}} \bullet V_{\text{SWING}} \bullet f_{\text{OSC}}$$

where C_{LOAD} is the 5pF load capacitance, V_{SWING} is the voltage swing, in this case up to 5.5V, and f_{OSC} is the frequency of the oscillator output. Driving a 5.5V swing into a 5pF load at 8MHz takes an average of 220µA. To calculate the portion of the supply current needed for a 50pF load, simply substitute 50pF for C_{LOAD} in the same equation:

50pF • 5.5V • 8MHz = 2.2mA

The majority of this power is expended during the rise and fall time of the output signal, not while it is in a steady



APPLICATIONS INFORMATION

state. The 2ns rise and fall times of the LTC6930 mean that the instantaneous power supply current required during the rise and fall portions of the waveform is much greater than the average.

The instantaneous power supply current may be calculated by a similar formula:

$$I_{PEAK} = C_{LOAD} \bullet V_{SWING} \bullet \frac{1}{t_{rf}}$$

where t_{rf} is the rise/fall time of the signal. In this case, 14mA spikes are generated by driving 5.5V into a 5pF load.

Power is supplied to the output driver of the LTC6930 from the V⁺ and GND pins on each side of the output pin (Pins 6 and 8). Allowances must be made in the design to provide for output load related supply current spikes, especially in high accuracy applications. A 0.1μ F ceramic capacitor connected between V⁺ and GND (Pins 6 and 8) as close as possible to the device will decouple the rest of the circuit from spikes caused by powering a capacitive output load of up to 50pF. See Figure 1.

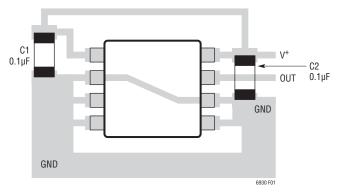


Figure 1. Recommended Layout

Switching the DIV Pins

The LTC6930 is designed to quickly and cleanly respond to the digital inputs. The output will respond to the DIV pins within a single clock cycle without introducing any sliver or runt pulses.

Start-Up Time

The start-up time of the LTC6930 is typically 50µs from the time that valid power is applied to the first output pulse. The output is held low for the first 50µs to prevent any glitches, runt pulses, or invalid frequency output during start-up.

Long-Term Drift

Long-term stability of silicon oscillators is specified in ppm/ \sqrt{kHr} , which is typical of other silicon devices such as operational amplifiers and voltage references. Because drift in silicon-based oscillators is generated primarily by movement of ions in the silicon, most of the drift is accomplished early in the life of the device and the drift can be expected to level off in the long term. The ppm/ \sqrt{kHr} unit models this time variant decay. Crystal oscillators are often specified with drift measured in ppm/year because their drift mechanism is different. A comparison of various drift rates over a five year time period is shown in Figure 2.

When calculating the amount of drift to be expected, it is important to consider the entire time in the calculation, because the relationship to time is not linear. The drift for 5 years is not 5 times the drift for one year. A sample

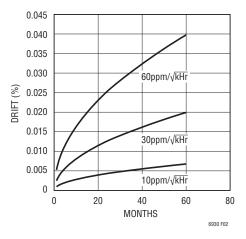


Figure 2. 5 Year Drift at Various Rates

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APPLICATIONS INFORMATION

calculation for drift over 5 years at $30ppm/\sqrt{kHr}$ is as follows:

5 years • 365.25 days/year • 24 hours/day = 43,830 hours = 43.830kHr

 $\sqrt{43.830\text{kHr}} = 6.62\sqrt{\text{kHr}}$

 $6.62\sqrt{kHr} \cdot 30ppm/\sqrt{kHr} = 0.0198\%$ over 5 years.

Drift calculations assume that the part is in continuous operation during the entire time period of the calculation. The movement of ions which results in drift is usually aided by electric fields in the operating parts, and the typical drift spec applies while the part is powered up. Conservative calculations would use a tenth of the drift specification for time when power is not applied to the part.

Setting the Frequency

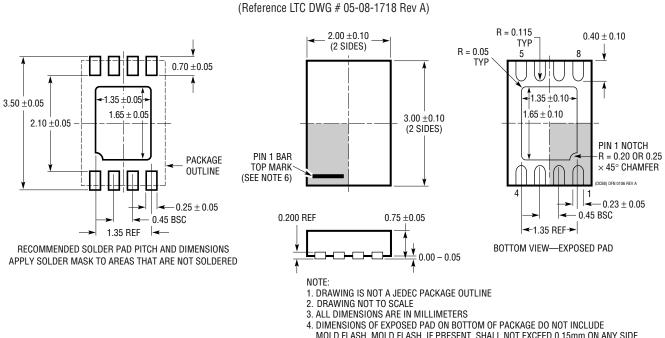
The output frequency of the LTC6930 is chosen from the values in Table 1 and set using the DIV pins, as noted in the table. Master oscillator frequency is preset in the factory, and the DIV pins select an internal binary divider of up to 128.

For example, if the desired oscillator output frequency is 2.5MHz, finding 2.5MHz in Table 1 shows that the LTC6930-5.00 should be ordered, having a master oscillator frequency of 5MHz, and a DIV value of [001] should be used. This would equate to grounding DIVC and DIVB, while connecting DIVA to the positive supply. Frequencies other than those shown in Table 1 may be requested.

Table 1. Frequency Setting and Available Frequencies

	÷1	÷2	÷4	÷8	÷16	÷32	÷64	÷128
DIV Pin Settings [DIVC][DIVB][DIVA]	000	001	010	011	100	101	110	111
LTC6930-4.19	4.194304MHz	2.097152MHz	1.048576MHz	524.288kHz	262.144kHz	131.072kHz	65.536kHz	32.768kHz
LTC6930-5.00	5.000MHz	2.500MHz	1.250MHz	625.0kHz	312.5kHz	156.25kHz	78.125kHz	39.0625kHz
LTC6930-7.37	7.3728MHz	3.6864MHz	1.8432MHz	921.6kHz	460.8kHz	230.4kHz	115.2kHz	57.6kHz
LTC6930-8.00	8.000MHz	4.000MHz	2.000MHz	1000kHz	500.0kHz	250.0kHz	125.0kHz	62.5kHz
LTC6930-8.19	8.192MHz	4.096MHz	2.048MHz	1024kHz	512.0kHz	256.0kHz	128.0kHz	64.0kHz

PACKAGE DESCRIPTION



DCB Package 8-Lead Plastic DFN ($2mm \times 3mm$)

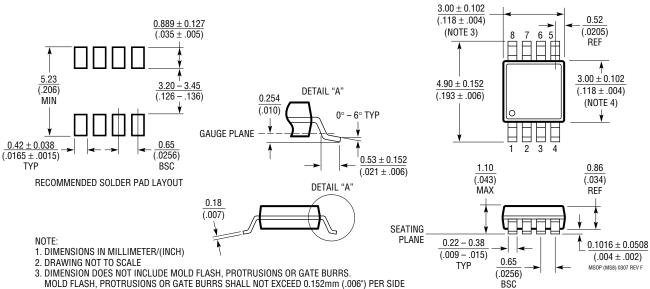
MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE

5. EXPOSED PAD SHALL BE SOLDER PLATED

6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

MS8 Package 8-Lead Plastic MSOP

(Reference LTC DWG # 05-08-1660 Rev F)

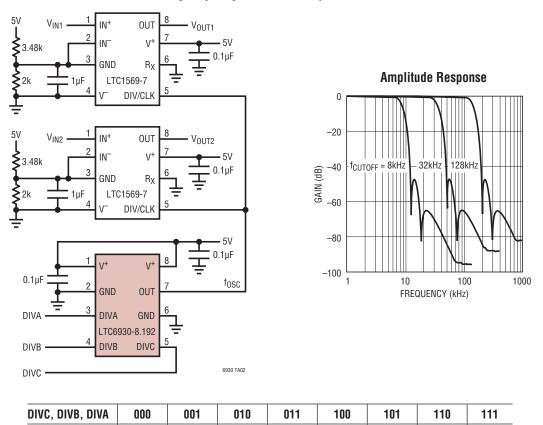


DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX



Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

TYPICAL APPLICATION



Dual, Matched, Digitally Programmable, Lowpass Filter, 2kHz to 256kHz

RELATED PARTS

f_{CUTOFF}

256kHz

128kHz

64kHz

32kHz

16kHz

8kHz

DESCRIPTION	COMMENTS
1kHz to 33MHz ThinSOT Oscillator, Resistor Set	Wide Frequency Range
1kHz to 20MHz ThinSOT Oscillator, Resistor Set	Low Power, Wide Frequency Range
Multiphase Oscillator with Spread Spectrum Modulation	2-, 3- or 4-Phase Outputs
1kHz to 68MHz Serial Port Programmable Oscillator	0.1% Frequency Resolution, I ² C or SPI Interface
17MHz to 170MHz ThinSOT Oscillator, Resistor Set	High Frequency, 100µs Start-Up, 7ps RMS Jitter
Fixed Frequency ThinSOT Oscillator Family, up to 133MHz	No Trim Components Required
Micropower 10kHz to 1MHz ThinSOT Oscillator, Resistor Set	12µA Supply Current at 100kHz, 0.65% Frequency Accuracy
Micropower 40kHz to 4MHz ThinSOT Oscillator, Resistor Set	36µA Supply Current at 400kHz, 0.65% Frequency Accuracy
Multiphase Oscillator with Spread Spectrum Modulation	2 Outputs Shifted by Either 180° or 90°
	1kHz to 33MHz ThinSOT Oscillator, Resistor Set 1kHz to 20MHz ThinSOT Oscillator, Resistor Set Multiphase Oscillator with Spread Spectrum Modulation 1kHz to 68MHz Serial Port Programmable Oscillator 17MHz to 170MHz ThinSOT Oscillator, Resistor Set Fixed Frequency ThinSOT Oscillator Family, up to 133MHz Micropower 10kHz to 1MHz ThinSOT Oscillator, Resistor Set Micropower 40kHz to 4MHz ThinSOT Oscillator, Resistor Set



2kHz

4kHz